



APT13005S

#### **Features**

- BV<sub>CEO</sub> > 450V
- BV<sub>CES</sub> > 700V
- BV<sub>EBO</sub> > 9V
- I<sub>C</sub> = 3.2A High Continuous Collector Current
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

# Applications

Low Power AC-DC SMPS for:

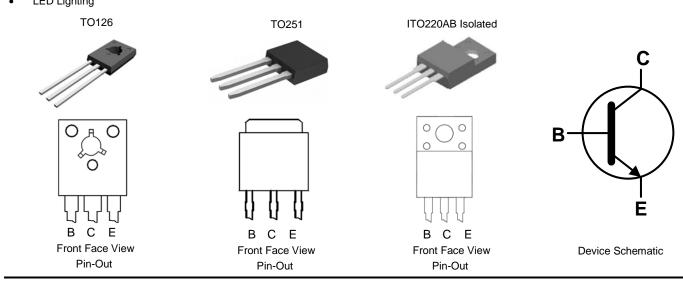
- Battery Chargers for Mobile Phone / Tablets / Smartphones
- Power Supply for DVD / STB
- LED Lighting

## Mechanical Data

- Case: TO126, TO251 or ITO220AB
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0

450V NPN HIGH VOLTAGE POWER TRANSISTOR

- Terminals: Matte Tin Finish; Solderable per MIL-STD-202, Method 208
  - Weight: TO126: 400mg (Approximate) TO251: 340mg (Approximate) ITO220AB: 1500mg (Approximate)



#### Ordering Information (Note 4)

Product	Package	Marking	Quantity
APT13005SU-G1	TO126	GU13005S	4,000 Bulk, Loose per Box
APT13005SI-G1	TO251	APT13005SI-G1	3,600 per Box in Tubes
APT13005STF-G1	ITO220AB	APT13005STF-G1	1,000 per Box in Tubes

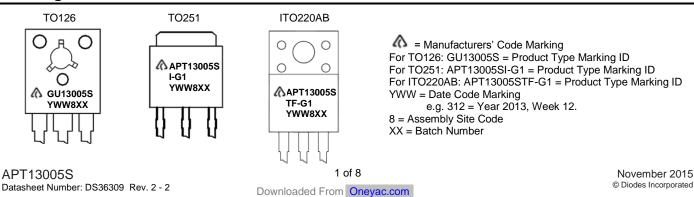
Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied. 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

See http://www and Lead-free.

Alalogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and</li>
<1000ppm antimony compounds.</li>

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### Marking Information





# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage (V <sub>BE</sub> = 0V)	V <sub>CES</sub>	700	V
Collector-Emitter Voltage	V <sub>CEO</sub>	450	V
Emitter-Base Voltage	V <sub>EBO</sub>	9	V
Continuous Collector Current	Ι <sub>C</sub>	3.2	А
Peak Pulse Collector Current	Ісм	6.4	А
Continuous Base Current	Ι <sub>Β</sub>	1.6	А
Peak Pulse Base Current	I <sub>BM</sub>	3.2	А

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
	For TO126 @T <sub>C</sub> = +25°C		20		
Power Dissipation	For TO251 @T <sub>C</sub> = +25°C	PD	25	W	
	For ITO220AB @T <sub>C</sub> = +25°C		28		
	For TO126		6.25	°C/W	
Thermal Resistance, Junction to Case	For TO251	R <sub>ejc</sub>	5.0		
	For ITO220AB		4.5		
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C	

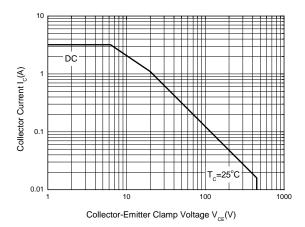
# ESD Ratings (Note 5)

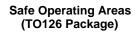
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

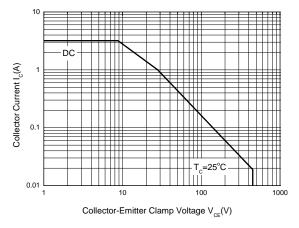
Note: 5. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



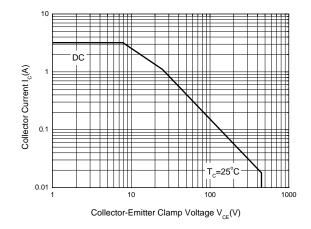
#### Safe Operating Areas (@T<sub>A</sub> = +25°C, unless otherwise specified.)







Safe Operating Areas (ITO220AB Package)



Safe Operating Areas (TO251 Package)



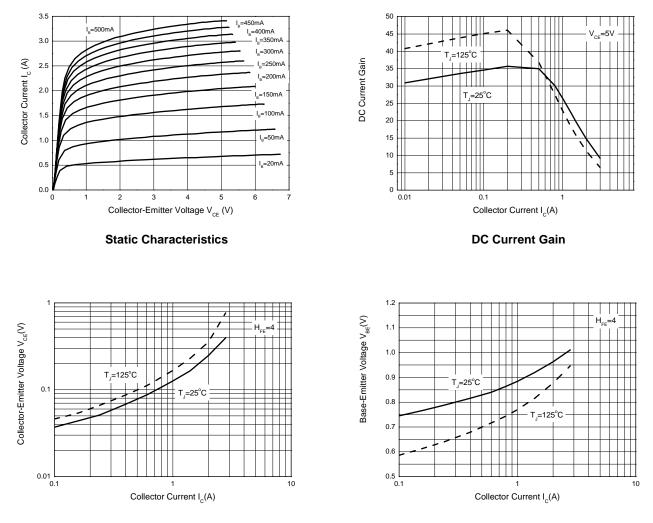
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

			_			
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>	700	—	—	V	$I_{C} = 100 \mu A, V_{BE} = 0 V$
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	450	—	—	V	$I_{C} = 100 \mu A$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	9	—	_	V	$I_E = 100 \mu A$
Collector Cutoff Current	I <sub>CEV</sub>		—	10	μA	$V_{CE} = 700V, V_{BE} = -1.5V$
DC Current Transfer Static Ratio (Note 6)	h	20	_	35		$I_{C} = 1A, V_{CE} = 5V$
	h <sub>FE</sub>	11	—	35		$I_C = 2A, V_{CE} = 5V$
			_	0.3		$I_{C} = 1A, I_{B} = 0.2A$
Collector-Emitter Saturation Voltage (Note 6)	V <sub>CE(sat)</sub>	—	—	0.6		$I_{\rm C} = 2A, I_{\rm B} = 0.5A$
		_	—	1.0		$I_{C} = 3A, I_{B} = 0.75A$
Base-Emitter Saturation Voltage (Note 6)	V <sub>BE(sat)</sub>		_	1.2	V	$I_{C} = 1A, I_{B} = 0.2A$
Base-Emilier Saturation Voltage (Note 6)		-	—	1.4		$I_{C} = 2A, I_{B} = 0.5A$
Output Capacitance	C <sub>OB</sub>	-	35	—	pF	$V_{CB} = 10V, f = 0.1MHz$
Transition Frequency	f <sub>T</sub>	4	_	_	MHz	I <sub>C</sub> = 0.5A, V <sub>CE</sub> = 10V
Turn-on Time with Resistive Load	t <sub>on</sub>	_	—	0.7		
Storage Time with Resistive Load	ts	_	_	4.5	μs	I <sub>C</sub> = 2A, V <sub>CC</sub> = 125V, I <sub>B1</sub> = -I <sub>B2</sub> = 0.4A
Fall Time with Resistive Load	t <sub>f</sub>	_	—	0.8	1	$I_{B1} = -I_{B2} = 0.4A$

Note: 6. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)



Collector-Emitter Saturation Region

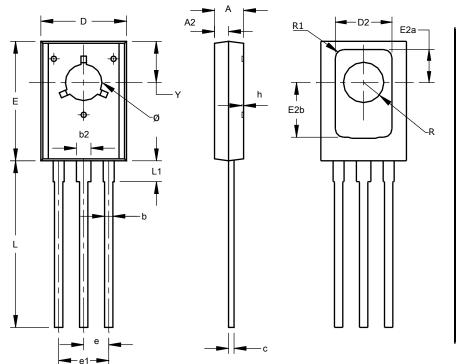
**Base-Emitter Saturation Voltage** 



# **Package Outline Dimensions**

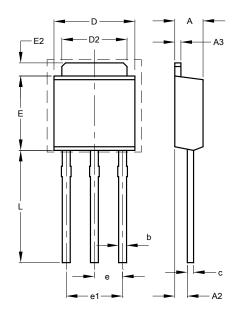
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

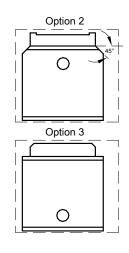
#### (1) Package Type: TO126



TO126					
Dim	Min	Мах	Тур		
Α	2.400	2.900	-		
A2	1.060	1.500	-		
b	0.660	0.860	-		
b2	1.170	1.470	-		
С	0.400	0.600	-		
D	7.400	8.200	-		
D2	5.010	5.310	-		
E	10.60	11.20	-		
E2a	2.850	3.150	-		
E2b	4.850	5.150	-		
е	-	-	2.280		
e1	-	-	4.560		
h	0.00	0.30	-		
L	14.50	15.90	-		
L1	1.700	2.100	-		
R	-	-	1.840		
R1	-	-	0.760		
Y	3.600	3.900	-		
Ø	3.100	3.550	-		
All Dimensions in mm					

#### (2) Package Type: TO251





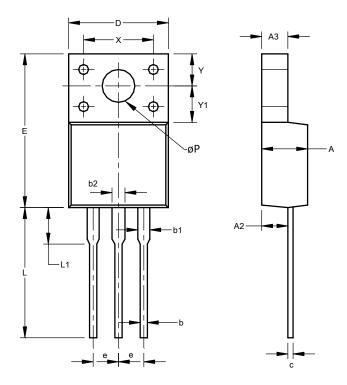
TO251				
Dim	Dim Min Ma			
Α	2.200	2.400		
A2	0.890	1.150		
A3	0.450	0.550		
b	0.550	0.740		
С	0.450	0.570		
D	6.400	6.750		
D2	5.200	5.400		
Е	5.950 6.250			
E2 0.900 1.250				
е	2.240	2.340		
e1	4.430 4.730			
L	8.900	9.500		
All Dimensions in mm				



#### Package Outline Dimensions (continued)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

#### (3) Package Type: ITO220AB (TYPE BR)



ITC	ITO220AB (TYPE BR)					
Dim	Min	Max	Тур			
Α	4.300	4.900	-			
A2	2.520	2.920	-			
A3	2.350	2.900	-			
b	0.550	0.900	-			
b1	1.000	1.400	-			
b2	1.100	1.500	-			
С	0.450	0.600	-			
D	9.70	10.30	-			
Е	14.70	16.00	-			
е	-	-	2.54			
L	12.50	13.50	-			
L1	2.790	4.500	-			
Х	6.90	7.10	-			
Y	3.000	3.400	-			
Y1	3.370	3.900	-			
øP	3.000	3.550	-			
All Dimensions in mm						

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals.



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